# **NCE P-Channel Super Trench Power MOSFET**

## **Description**

The NCEP40P65GU uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification

# **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

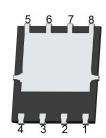
## **General Features**

- $V_{DS}$  =-40V, $I_D$  =-65A  $R_{DS(ON)}$ =7.8m $\Omega$  (typical) @  $V_{GS}$ =-10V  $R_{DS(ON)}$ =11.5m $\Omega$  (typical) @  $V_{GS}$ =-4.5V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 150 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!

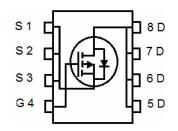
#### **DFN 5X6**





**Top View** 

**Bottom View** 



**Schematic Diagram** 

## **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P40P65GU	NCEP40P65GU	DFN5X6-8L	-	-	-

# Absolute Maximum Ratings (T<sub>C</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	-40	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub> (T <sub>C</sub> =25°C)	-65	Α
Drain Current-Continuous(T <sub>C</sub> =100°ℂ)	I <sub>D</sub> (T <sub>C</sub> =100℃)	-46	Α
Pulsed Drain Current	I <sub>DM</sub>	-260	Α
Maximum Power Dissipation(T <sub>C</sub> =25°ℂ)	P <sub>D</sub> (T <sub>C</sub> =25°C)	85	W
Pulsed Drain Current	I <sub>DM</sub>	-260	Α
Derating factor		0.68	W/℃
Single pulse avalanche energy (Note 1)	E <sub>AS</sub>	423	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	$^{\circ}\!\mathbb{C}$

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case	ReJC	1.47	°C/W

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# NCEP40P65GU

# Electrical Characteristics (T<sub>C</sub>=25 ℃ unless otherwise noted)

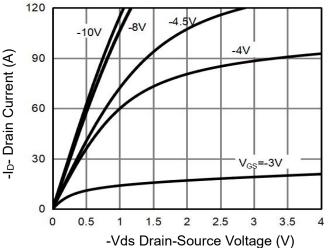
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-40		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-40V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20 $V$ , $V_{DS}$ =0 $V$	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250μA	-1.0	-1.7	-2.5	V
Drain-Source On-State Resistance	Б	V <sub>GS</sub> =-10V, I <sub>D</sub> =-20A	-	7.8	10.0	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-20A	-	11.5	16.0	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-5V,I <sub>D</sub> =-20A	-	30	-	S
Dynamic Characteristics						
Input Capacitance	Clss	V <sub>DS</sub> =-20V,V <sub>GS</sub> =0V, F=1.0MHz	-	2450	-	PF
Output Capacitance	Coss		-	660	-	PF
Reverse Transfer Capacitance	Crss	F-1.UIVITZ	-	18	-	PF
Switching Characteristics (Note 2)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	9	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =-20V, $I_{D}$ =-20A	-	4	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =-10 $V$ , $R_{G}$ =1.6 $\Omega$	-	30	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	5	-	nS
Total Gate Charge	Qg	\/ 00\/ L 00A	-	39	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =-20V, $I_{D}$ =-20A, $V_{GS}$ =-10V	-	7.8		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =-10V	-	5.3		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-20A	-		-1.2	V
Diode Forward Current	Is		-	-	-65	А
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> =-20A	-	22		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/μs	-	58		nC

### Notes:

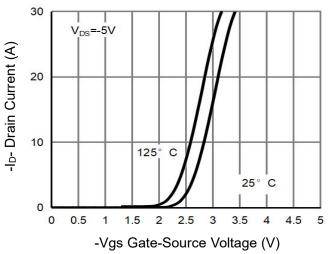
- 1. EAS condition : Tj=25  $^{\circ}\text{C}$  ,VDD=-20V,VG=-10V,L=0.5mH,Rg=25 $\Omega$
- 2. Guaranteed by design, not subject to production
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=150°C. The SOA curve provides a single pulse rating.



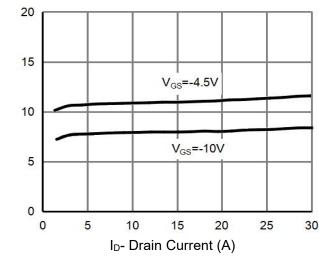




**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 



Rdson On-Resistance(m \( \Omega \))

Figure 3 Rdson- Drain Current

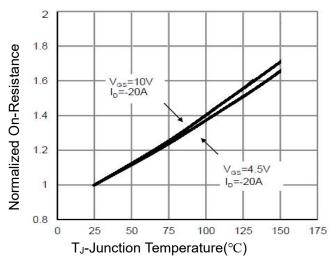


Figure 4 Rdson-JunctionTemperature

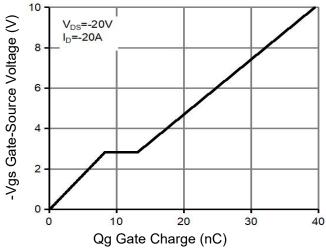


Figure 5 Gate Charge

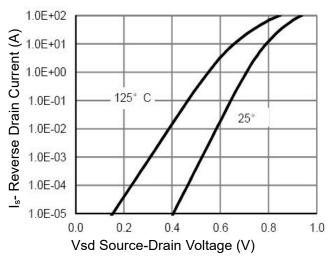


Figure 6 Source- Drain Diode Forward



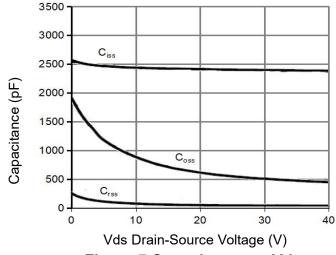


Figure 7 Capacitance vs Vds

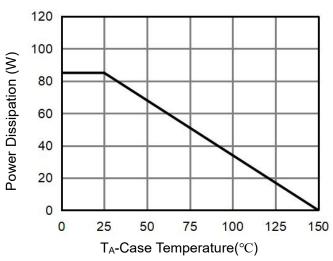


Figure 9 Power De-rating

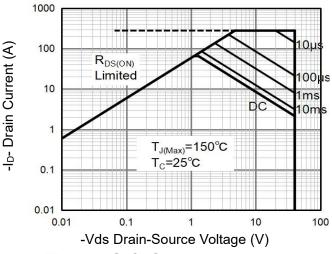


Figure 8 Safe Operation Area

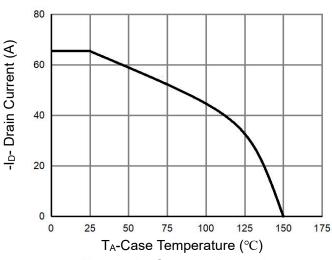


Figure 10 Current De-rating

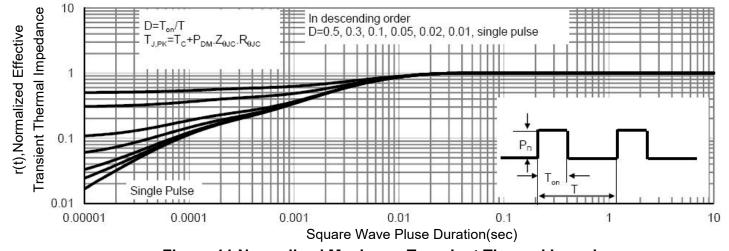
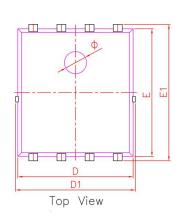
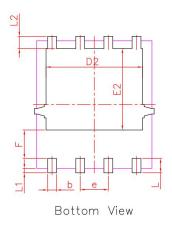


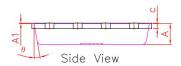
Figure 11 Normalized Maximum Transient Thermal Impedance



# **DFN5X6-8L Package Information**







PDFN5X6-8L					
DIM.	MIN.	NOM.	MAX.		
Α	0.90	0.95	1.00		
A1	0.00	0.02	0.05		
Ь	0.35	0.40	0.50		
С	0.20	0.25	0.30		
D	5.10	5.20	5.30		
D1	5.10	5.40	5.50		
D2	4.25	4.35	4.45		
е	1.27 BSC				
Е	5.70	5.75	5.80		
E1	6.00	6.15	6.30		
E2	3.57	3.67	3.77		
F	1.18	1.28	1.38		
L	0.55	0.65	0.75		
L1	0.15	0.20	0.25		
L2	0.45	0.55	0.65		
ø	0.90	1.00	1.10		
Θ	8*	10°	12°		
All dimensions in millimeters					

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# NCEP40P65GU

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